

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(ON) \text{ max}}$ | $I_D \text{ max}$ $T_A = +25^\circ\text{C}$ |
|---------------|---------------------------------|--|
| -40V | 80mΩ @ $V_{GS} = -10\text{V}$ | -3.7 A |
| | 150mΩ @ $V_{GS} = -4.5\text{V}$ | -2.8 A |

Description

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

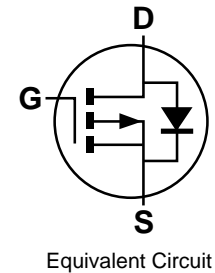
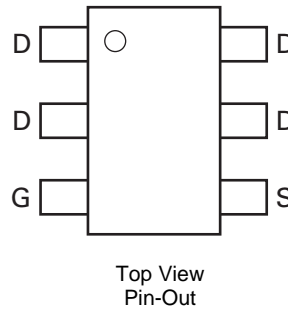
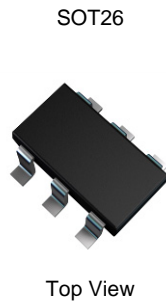
- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

Features and Benefits

- Fast switching speed
- Low gate drive
- Low input capacitance
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 **e3**
- Weight 0.018 grams (approximate)

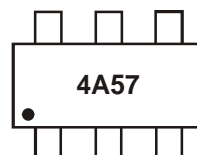


Ordering Information (Note 4 & 5)

| Part Number | Compliance | Case | Quantity per reel |
|---------------|------------|-------|-------------------|
| ZXMP4A57E6TA | Standard | SOT26 | 3,000 |
| ZXMP4A57E6QTA | Automotive | SOT26 | 3,000 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



4A57 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

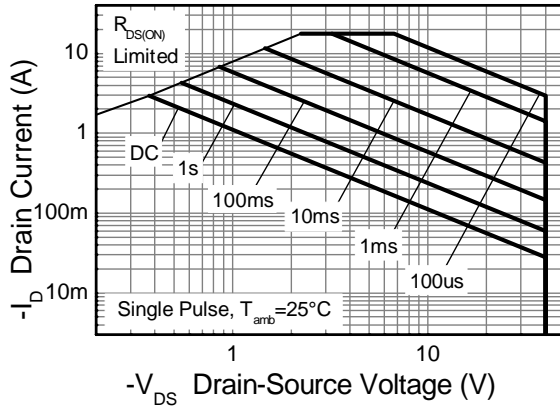
| Characteristic | | | Symbol | Value | Unit |
|--|-----------------------|---------------------------------|------------------|-------|------|
| Drain-Source Voltage | | | V _{DSS} | -40 | V |
| Gate-Source Voltage | | | V _{GS} | ±20 | V |
| Continuous Drain Current | V _{GS} = 10V | (Note 7) | I _D | -3.7 | A |
| | | T _A = +70°C (Note 7) | | -2.9 | |
| | | (Note 6) | | -2.9 | |
| Pulsed Drain current | V _{GS} = 10V | (Note 8) | I _{DM} | -18 | A |
| Continuous Source Current (Body Diode) | | (Note 7) | I _S | -2.6 | A |
| Pulsed Source Current (Body Diode) | | (Note 8) | I _{SM} | -18 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

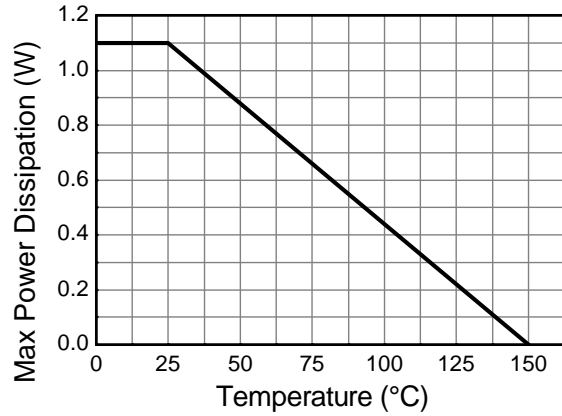
| Characteristic | | Symbol | Value | Unit |
|---|----------|-----------------------------------|-------------|------------|
| Power dissipation Linear derating factor | (Note 6) | P _D | 1.1 | W mW/°C |
| | | | 8.8 | |
| | (Note 7) | | 1.7 13.7 | |
| Thermal Resistance, Junction to Ambient | (Note 6) | R _{θJA} | 113 | °C/W |
| | (Note 7) | | 73 | |
| Operating and storage temperature range | | T _J , T _{STG} | -55 to +150 | °C |

- Notes:
6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 7. Same as note (4), except the device is measured at t ≤ 5 sec.
 8. Same as note (4), except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.

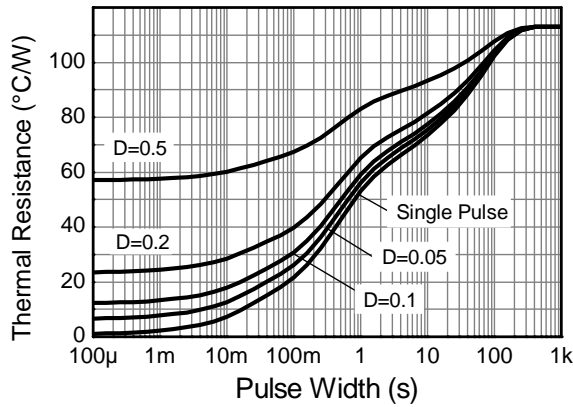
Thermal Characteristics



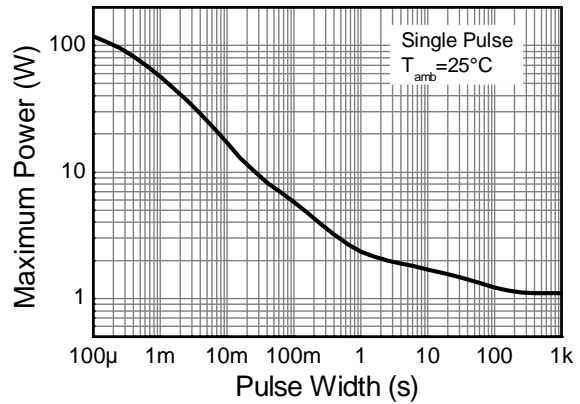
P-channel Safe Operating Area



Derating Curve



Transient Thermal Impedance



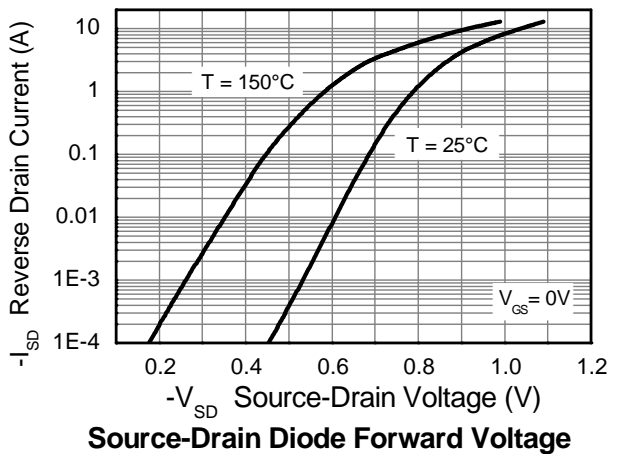
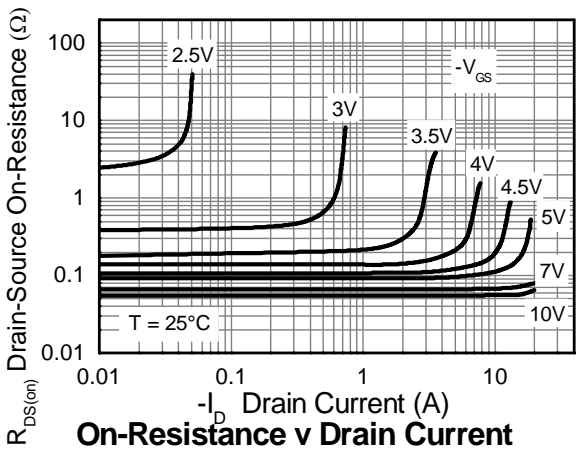
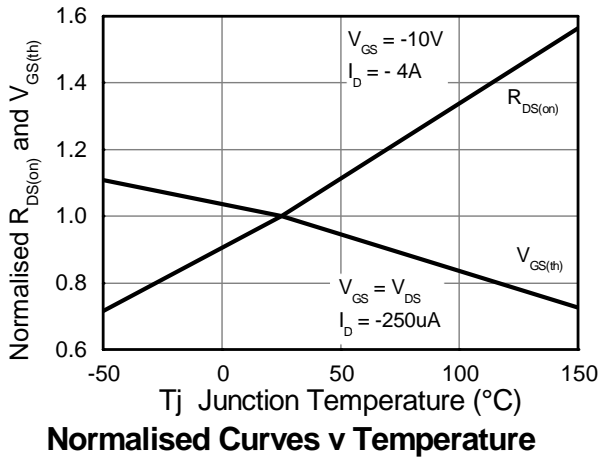
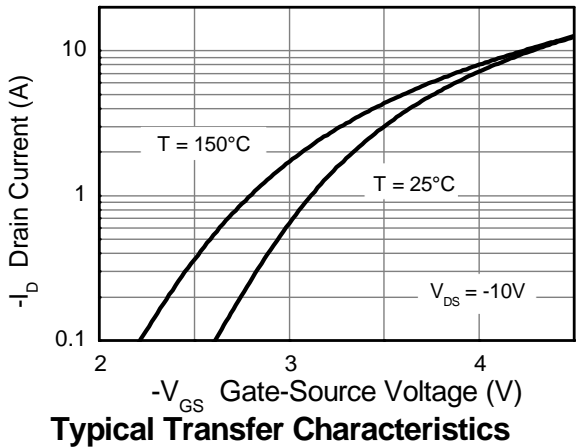
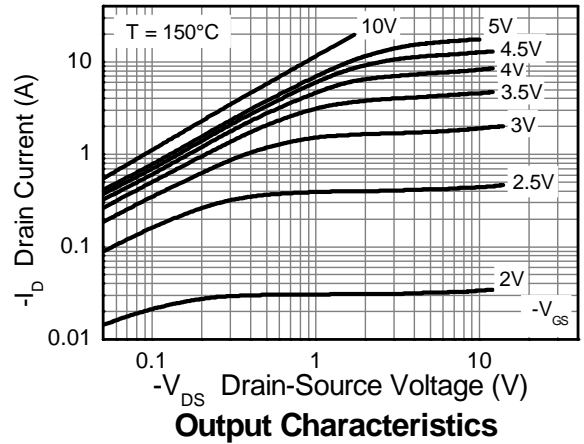
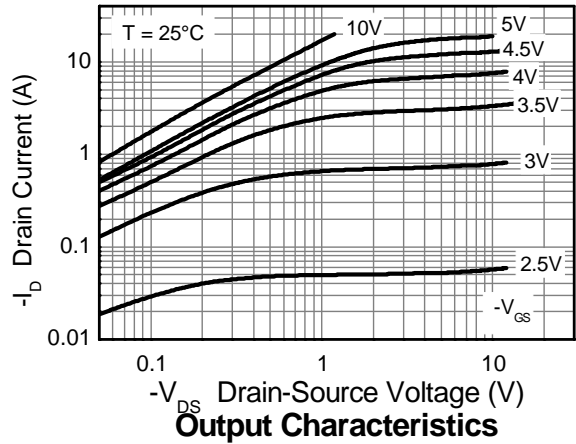
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

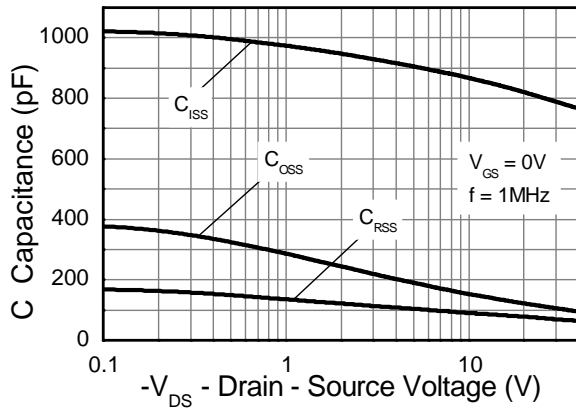
| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition | |
|--|---------------------|------|-------|-------|------|---|--|
| OFF CHARACTERISTICS | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -40 | — | — | V | I _D = -250μA, V _{GS} = 0V | |
| Zero Gate Voltage Drain Current | I _{DSS} | — | — | -0.5 | μA | V _{DS} = -40V, V _{GS} = 0V | |
| Gate-Source Leakage | I _{GSS} | — | — | ±100 | nA | V _{GS} = ±20V, V _{DS} = 0V | |
| ON CHARACTERISTICS | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -1.0 | — | -3.0 | V | I _D = -250μA, V _{DS} = V _{GS} | |
| Static Drain-Source On-Resistance (Note 9) | R _{DS(ON)} | — | — | 0.080 | Ω | V _{GS} = -10V, I _D = -4A | |
| | | — | — | 0.150 | | V _{GS} = -4.5V, I _D = -2A | |
| Forward Transconductance (Notes 9 & 10) | g _{fs} | — | 7.6 | — | S | V _{DS} = -15V, I _D = -4A | |
| Diode Forward Voltage (Note 9) | V _{SD} | — | -0.86 | -0.95 | V | I _S = -4A, V _{GS} = 0V | |
| Reverse recovery time (Note 10) | t _{rr} | — | 17.4 | — | ns | I _S = -1.8A, di/dt = 100A/μs | |
| Reverse recovery charge (Note 10) | Q _{rr} | — | 11.1 | — | nC | | |
| DYNAMIC CHARACTERISTICS (Note 10) | | | | | | | |
| Input Capacitance | C _{iss} | — | 833 | — | pF | V _{DS} = -20V, V _{GS} = 0V f = 1MHz | |
| Output Capacitance | C _{oss} | — | 122 | — | | | |
| Reverse Transfer Capacitance | C _{rss} | — | 78 | — | | | |
| Total Gate Charge (Note 11) | Q _g | — | 7 | — | nC | V _{GS} = -4.5V | |
| Total Gate Charge (Note 11) | Q _g | — | 15.8 | — | | V _{GS} = -10V | V _{DS} = -20V I _D = -4A |
| Gate-Source Charge (Note 11) | Q _{gs} | — | 3.6 | — | | | |
| Gate-Drain Charge (Note 11) | Q _{gd} | — | 2.7 | — | | | |
| Turn-On Delay Time (Note 11) | t _{D(on)} | — | 2.5 | — | ns | V _{DD} = -20V, V _{GS} = -10V I _D = -1A, R _G ≅ 6.0Ω | |
| Turn-On Rise Time (Note 11) | t _r | — | 3.3 | — | | | |
| Turn-Off Delay Time (Note 11) | t _{D(off)} | — | 47 | — | | | |
| Turn-Off Fall Time (Note 11) | t _f | — | 21 | — | | | |

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
 10. For design aid only, not subject to production testing.
 11. Switching characteristics are independent of operating junction temperatures.

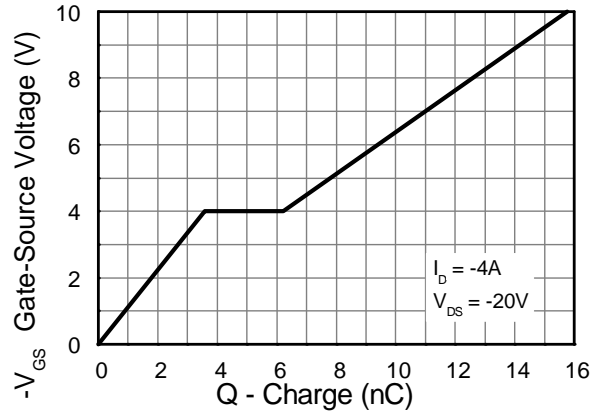
Typical Characteristics



Typical Characteristics (cont.)

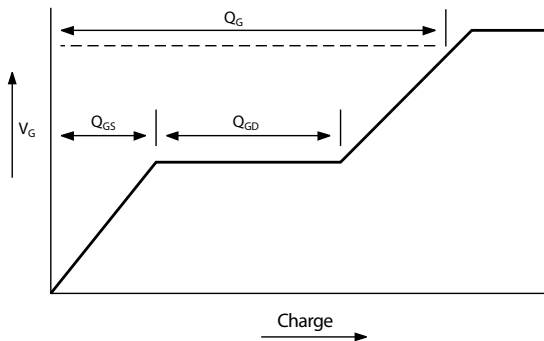


Capacitance v Drain-Source Voltage

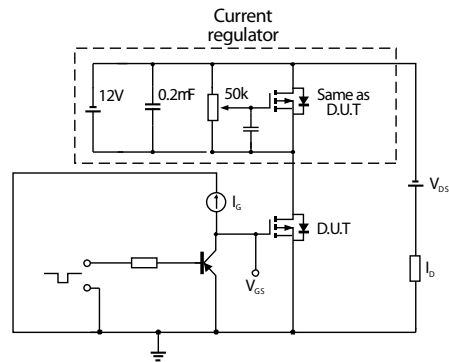


Gate-Source Voltage v Gate Charge

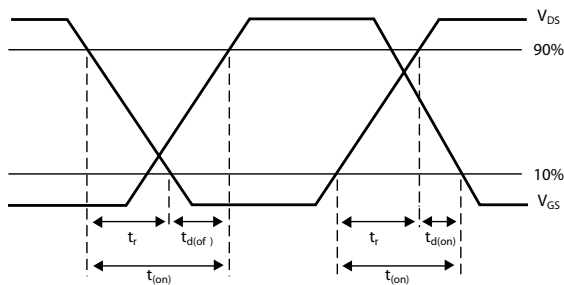
Test Circuits



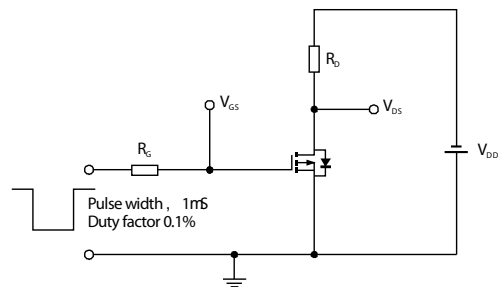
Basic gate charge waveform



Gate charge test circuit



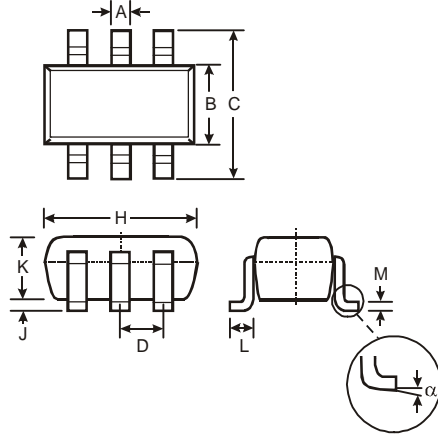
Switching time waveforms



Switching time test circuit

Package Outline Dimensions

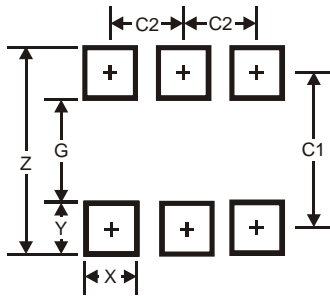
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT26 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 0.35 | 0.50 | 0.38 |
| B | 1.50 | 1.70 | 1.60 |
| C | 2.70 | 3.00 | 2.80 |
| D | — | — | 0.95 |
| H | 2.90 | 3.10 | 3.00 |
| J | 0.013 | 0.10 | 0.05 |
| K | 1.00 | 1.30 | 1.10 |
| L | 0.35 | 0.55 | 0.40 |
| M | 0.10 | 0.20 | 0.15 |
| α | 0° | 8° | — |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 3.20 |
| G | 1.60 |
| X | 0.55 |
| Y | 0.80 |
| C1 | 2.40 |
| C2 | 0.95 |

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